

# Cypress Semiconductor Product Qualification Report

QTP# 142304 VERSION \*A  
July 2014

<b>PSoC4 Family</b>	
<b>S8PF-10R, Fab 3 HHGrace</b>	
<b>CY8C4013 CY8C4014</b>	<b>Programmable System-on-Chip (PSoC)</b>

FOR ANY QUESTIONS ON THIS REPORT, PLEASE CONTACT  
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## PRODUCT QUALIFICATION HISTORY

<b>QTP Number</b>	<b>Description of Qualification Purpose</b>	<b>Date</b>
090706	Qualification of Capsense (CY8C20X36A, CY8C20X46A, CY8C20X66A, CY8C20X96A) Device in Fab 5 GSMC on S8DIN-5R Process	Mar 10
100101	Qualification of Touch Screen PSoC Device in S8TMC-5R Process at GSMC	Apr 10
124505	Qualification of 5th Generation Touch Screen (TSG5_M) device using S8P12-10P technology at GSMC-Fab 5	May 13
142304	Qualification of CY8C4013/ CY8C4014 PSoC4 Family, S8PF-10R Technology in HHGrace-Fab3	June 14



PRODUCT DESCRIPTION (for qualification)	
Qualification Purpose: To Qualify CapSense Controller device family, S8PF-10R Technology in HHGrace Fab3	
Marketing Part #:	CY8C4013 / CY8C4014
Device Description:	5V, Industrial Programmable System on a Chip
Cypress Division:	Cypress Semiconductor Corporation – Programmable System Division (PSD)

TECHNOLOGY/FAB PROCESS DESCRIPTION			
Number of Metal Layers:	5	Metal Composition:	Metal 1: 150A Ti /250A TiN / 3200Al-0.5%Cu / 90A Ti/500A TiN Metal 2: 150A Ti /250A TiN/ 3200Al-0.5%Cu / 90A Ti/500A TiN Metal 3: 150A Ti /250A TiN 6500Al-0.5%Cu / 90A Ti/500A TiN Metal 4: 150A Ti /250A TiN 6500Al-0.5%Cu / 90A Ti/500A TiN Metal 5: 190A Ti/450A TiN/10000A Al-0.5% Cu/90A Ti/200A TiN
Passivation Type and Thickness:		NFUSOX / 1K oxide / 6k Nitride	
Generic Process Technology/Design Rule ( $\mu$ -drawn):		S8PF-10R	
Gate Oxide Material/Thickness (MOS):		SiO <sub>2</sub> / 32A/110A	
Name/Location of Die Fab (prime) Facility:		Fab 3 / HHGrace, Shanghai China	
Die Fab Line ID/Wafer Process ID:		S8PF-10R	

### ALTERNATIVE FAB FACILITY SITE

FAB SITE	LOCATION	QTP NUMBER
CMI Fab 4	MINNESOTA, USA	132802

### PACKAGE AVAILABILITY

PACKAGE	ASSEMBLY FACILITY SITE	WIRE	QTP NUMBER
16-Lead QFN	CML-RA	CuPd	140804
16-Lead QFN	ASE-K	CuPd	134505
16/24 -Lead QFN	UTL-UT	CuPd	141704
8-Lead SOIC	UTL-UT	CuPd	134513
16-Lead SOIC	UTL-UT	CuPd	134506
28-Lead SSOP	CML-RA	CuPd	145006
28-Lead SSOP	JCET-JT	CuPd	145005

Note: **Package Qualification details upon request.**

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<b>MAJOR PACKAGE INFORMATION USED IN THIS QUALIFICATION</b>	
<b>Package Designation:</b>	LQ44A, LQ48A
<b>Package Outline, Type, or Name:</b>	44 & 48 Quad Flat No-Lead (QFN)
<b>Mold Compound Name/Manufacturer:</b>	7470LA / Nitto
<b>Mold Compound Flammability Rating:</b>	UL94 – V0
<b>Oxygen Rating Index:</b>	None
<b>Lead Frame Material:</b>	Copper
<b>Lead Finish, Composition / Thickness:</b>	NiPdAu
<b>Die Backside Preparation Method/Metallization:</b>	Backgrind
<b>Die Separation Method:</b>	100% Saw
<b>Die Attach Supplier:</b>	Henkel
<b>Die Attach Material:</b>	QMI-519
<b>Die Attach Method:</b>	Epoxy
<b>Bond Diagram Designation:</b>	001-78882
<b>Wire Bond Method:</b>	Thermosonic
<b>Wire Material/Size:</b>	CuPd 0.8 mil
<b>Thermal Resistance Theta JA °C/W:</b>	31.36 C/W
<b>Package Cross Section Yes/No:</b>	N/A
<b>Assembly Process Flow:</b>	001-69810
<b>Name/Location of Assembly (prime) facility:</b>	CML-RA
<b>MSL Level</b>	3
<b>Reflow Profile</b>	260C

<b>ELECTRICAL TEST / FINISH DESCRIPTION</b>	
<b>Test Location:</b>	CML-RA, ASE-KH, UTAC-UT

**Note:** Please contact a Cypress Representative for other package availability.

## RELIABILITY TESTS PERFORMED PER SPECIFICATION REQUIREMENTS

Stress/Test	Test Condition (Temp/Bias)	Result P/F
High Temperature Operating Life Early Failure Rate (EFR)	Dynamic Operating Condition, 150°C, 2.1V, 48 Hours JESD22-A-108	P
High Temperature Operating Life Early Failure Rate (EFR) – Regulator On	Dynamic Operating Condition, 150°C, 2.1V/5.5V, 48 Hours JESD22-A-108	P
High Temperature Operating Life Latent Failure Rate (LFR)	Dynamic Operating Condition, 150°C, 2.1V, 500 Hours JESD22-A-108	P
High Temperature Steady State life	Static Operating Condition, 150°C, 5.75.V, Vcc Max JESD22-A-108	P
Low Temperature Operating Life	Dynamic Operating Condition, -30°C, 2.1V JESD22-A-108	P
Endurance	10K Cycles, Per datasheet, JESD22-A117	P
Data Retention	150°C, 1000 Hours JESD22-A117 and JESD22-A103	P
Temperature Cycle	MIL-STD-883, Method 1010, Condition C, -65 °C to 150°C Precondition: JESD22 Moisture Sensitivity Level 3 192 Hrs, 30C/60%RH+ Reflow, 260°C+0, -5°C	P
High Accelerated Saturation Test (HAST)	JEDEC STD 22-A110: 130°C, 85% RH, 5.25V/5.5V Precondition: JESD22 Moisture Sensitivity Level 3 192 Hrs, 30C/60%RH+ Reflow, 260°C+0, -5°C	P
Pressure Cooker	JESD22-A102:121°C /100%RH, 15 PSIG Precondition: JESD22 Moisture Sensitivity Level 3 192 Hrs, 30C/60%RH+ Reflow, 260°C+0, -5°C	P
Aged Bond Strength	200C, 4hrs MIL-STD-883, Method 883-2011	P
Electrostatic Discharge Human Body Model (ESD-HBM)	2200V/ 3300V/ 4000V/5000V/ 6000V, JESD22-A114	P
Electrostatic Discharge Charge Device Model (ESD-CDM)	500V/750V/ 1000V/ 1250V/ 1500V/1750V, JESD22-C101	P
Electrostatic Discharge Machine Model (ESD-MM)	200V, JESD22-A115	P
Dynamic Latch-Up	150°C, 9.0 V JESD78	P
Static Latch-up	± 140mA, 125°C/85°C, 8.25V ± 300mA, 85C, 9.1V JESD78	P
Acoustic Microscopy	J-STD-020 Precondition: JESD22 Moisture Sensitivity Level 3 192 Hrs, 30C/60%RH+ Reflow, 260°C+0, -5°C	P

### RELIABILITY FAILURE RATE SUMMARY

Stress/Test	Device Tested/ Device Hours	# Fails	Activation Energy	Thermal AF <sup>3</sup>	Failure Rate
High Temperature Operating Life Early Failure Rate	1,503	0	N/A	N/A	0 PPM <sup>1</sup>
High Temperature Operating Life Long Term Failure Rate	902,240 DHRs	0	0.7	170	6 FIT <sup>2</sup>

<sup>1</sup> Assuming an ambient temperature of 55°C and a junction temperature rise of 15°C.

<sup>2</sup> Chi-squared 60% estimations used to calculate the failure rate.

<sup>3</sup> Thermal Acceleration Factor is calculated from the Arrhenius equation

$$AF = \exp \left[ \frac{E_A}{k} \left[ \frac{1}{T_2} - \frac{1}{T_1} \right] \right]$$

where:

$E_A$  = The Activation Energy of the defect mechanism.

$K$  = Boltzmann's constant =  $8.62 \times 10^{-5}$  eV/Kelvin.

$T_1$  is the junction temperature of the device under stress and  $T_2$  is the junction temperature of the device at use conditions.

<sup>1</sup> Early Failure Rate was computed from QTPs 142304

<sup>2</sup> Long Term Failure Rate was computed from QTPs 090706, 100101, 124505 & 142304 LFR Data.



## Reliability Test Data

### QTP #: 090706

<i>Device</i>	<i>Fab Lot #</i>	<i>Assy Lot #</i>	<i>Assy Lot</i>	<i>Duration</i>	<i>Samp</i>	<i>Rej</i>	<i>Failure Mechanism</i>
<b>STRESS: ACOUSTIC, MSL3</b>							
CY8C20466A (8C204665A)	4926959	610927071	CML-RA	COMP	15	0	
CY8C20466A (8C204665A)	4934292	610931047	CML-RA	COMP	15	0	
CY8C20466A (8C204665A)	4938497	610935369	CML-RA	COMP	15	0	
<b>STRESS: AGE BOND STRENGTH</b>							
CY8C20466A (8C204665A)	4926959	610927071	CML-RA	COMP	3	0	
CY8C20466A (8C204665A)	4934292	610931047	CML-RA	COMP	3	0	
CY8C20466A (8C204665A)	4938497	610935369	CML-RA	COMP	3	0	
<b>STRESS: DATA RETENTION, PLASTIC, 150C</b>							
CY8C20466A (8C204665A)	4926959	610927071	CML-RA	500	77	0	
CY8C20466A (8C204665A)	4926959	610927071	CML-RA	1000	77	0	
CY8C20466A (8C204665A)	4926959	610927071	CML-RA	1446	77	0	
CY8C20466A (8C204665A)	4934292	610931047	CML-RA	500	80	0	
CY8C20466A (8C204665A)	4934292	610931047	CML-RA	1000	80	0	
CY8C20466A (8C204665A)	4938497	610935369	CML-RA	500	80	0	
CY8C20466A (8C204665A)	4938497	610935369	CML-RA	1000	80	0	
<b>STRESS: ENDURANCE</b>							
CY8C20566A (8C205665A)	4926959	610926865	CML-R	168	77	0	
CY8C20566A (8C205665A)	4926959	610926865	CML-R	524	77	0	
CY8C20566A (8C205665A)	4934292	610931057	CML-R	168	78	0	
CY8C20566A (8C205665A)	4938497	610935104	CML-R	168	77	0	
<b>STRESS: ESD-CHARGE DEVICE MODEL, (500V)</b>							
CY8C20066A (8C200665A)	4926959	610926836	Malaysia-CA	COMP	9	0	
CY8C20066A (8C200665A)	4934292	610932270	Malaysia-CA	COMP	9	0	
CY8C20066A (8C200665A)	4938497	610935356	Malaysia-CA	COMP	9	0	



## Reliability Test Data

**QTP #: 090706**

<b>Device</b>	<b>Fab Lot #</b>	<b>Assy Lot #</b>	<b>Assy Loc</b>	<b>Duration</b>	<b>Samp</b>	<b>Rej</b>	<b>Failure Mechanism</b>
<b>STRESS: ESD-HUMAN BODY CIRCUIT PER JESD22, METHOD A114-B, (2,200V)</b>							
CY8C20066A (8C200665A)	4926959	610926836	Malaysia-CA COMP		8	0	
CY8C20066A (8C200665A)	4934292	610932270	Malaysia-CA COMP		8	0	
CY8C20066A (8C200665A)	4938497	610935356	Malaysia-CA COMP		8	0	
<b>STRESS: STATIC LATCH-UP (125C, 8.25V, 140mA)</b>							
CY8C20066A (8C200665A)	4926959	610926836	Malaysia-CA COMP		6	0	
CY8C20066A (8C200665A)	4934292	610932270	Malaysia-CA COMP		6	0	
CY8C20066A (8C200665A)	4938497	610935356	Malaysia-CA COMP		6	0	
<b>STRESS: DYNAMIC LATCH-UP (150C, 9.0V)</b>							
CY8C20466A (8C204665A)	4926959	610927071	CML-RA COMP		5	0	
<b>STRESS: HIGH TEMP DYNAMIC OPERATING LIFE-EARLY FAILURE RATE (150, 2.1V, Vcc Max)</b>							
CY8C20466A (8C204665A)	4926959	610927071	CML-RA	48	1000	0	
CY8C20466A (8C204665A)	4934292	610931047	CML-RA	48	1000	0	
CY8C20466A (8C204665A)	4938497	610935369	CML-RA	48	1000	0	
<b>STRESS: HIGH TEMP DYNAMIC OPERATING LIFE-EARLY FAILURE RATE REGULATOR ON (150, 5.5V, Vcc Max)</b>							
CY8C20466A (8C204665A)	4926959	610927071	CML-RA	48	45	0	
<b>STRESS: HIGH TEMP DYNAMIC OPERATING LIFE-LATENT FAILURE RATE (150C, 2.1V, Vcc Max)</b>							
CY8C20466A (8C204665A)	4926959	610927071	CML-RA	80	400	0	
CY8C20466A (8C204665A)	4926959	610927071	CML-RA	500	399	0	
CY8C20466A (8C204665A)	4934292	610931047	CML-RA	500	444	0	
CY8C20466A (8C204665A)	4938497	610935369	CML-RA	80	400	0	
CY8C20466A (8C204665A)	4938497	610935369	CML-RA	500	400	0	
<b>STRESS: HIGH TEMP STEADY STATE LIFE TEST (150C, 5.75V)</b>							
CY8C20466A (8C204665A)	4926959	610927071	CML-RA	80	77	0	
CY8C20466A (8C204665A)	4926959	610927071	CML-RA	168	77	0	
<b>STRESS: LOW TEMPERATURE DYNAMIC OPERATING LIFE, -30C, 2.1V</b>							
CY8C20566A (8C205665A)	4926959	610926865	CML-R	500	83	0	





## Reliability Test Data

### QTP #: 090706

<i>Device</i>	<i>Fab Lot #</i>	<i>Assy Lot #</i>	<i>Assy Loc</i>	<i>Duration</i>	<i>Samp</i>	<i>Rej</i>	<i>Failure Mechanism</i>
<b>STRESS: HI-ACCEL SATURATION TEST (130C, 85%RH, 5.25V), PRE COND 192 HR 30C/60%RH (MSL3)</b>							
CY8C20466A (8C204665A)	4948407	GSMC610946935	CML-RA	128	80	0	
CY8C20466A (8C204665A)	4948407 <sup>a2</sup>	610947114	CML-RA	128	80	0	
CY8C20466A (8C204665A)	4948407 <sup>a3</sup>	611002233	CML-RA	128	80	0	
<b>STRESS: PRESSURE COOKER TEST (121C, 100%RH), 15 Psig, PRE COND 192 HR 30C/60%RH (MSL3)</b>							
CY8C20466A (8C204665A)	4948407	GSMC610946935	CML-RA	168	80	0	
CY8C20466A (8C204665A)	4948407 <sup>a2</sup>	610947114	CML-RA	168	80	0	
CY8C20466A (8C204665A)	4948407 <sup>a3</sup>	611002233	CML-RA	168	80	0	
<b>STRESS: TC COND. C -65C TO 150C, PRE COND 192 HRS 30C/60%RH (MSL3)</b>							
CY8C20466A (8C204665A)	4926959	610927071	CML-RA	500	76	0	
CY8C20466A (8C204665A)	4934292	610931047	CML-RA	500	80	0	
CY8C20466A (8C204665A)	4934292	610931047	CML-RA	1000	80	0	
CY8C20466A (8C204665A)	4938497	610935369	CML-RA	500	80	0	
<b>STRESS: SEM CROSS SECTION</b>							
CY8C20066A (8C20066AC)	4934292	610931047	CML-RA	COMP	1	0	



## Reliability Test Data

### QTP #:100101

<i>Device</i>	<i>Fab Lot #</i>	<i>Assy Lot #</i>	<i>Assy Lot</i>	<i>Duration</i>	<i>Samp</i>	<i>Rej</i>	<i>Failure Mechanism</i>
<b>STRESS: ACOUSTIC, MSL3</b>							
CY8CTMA300EES	4016083	611028818	MB-PHIL	COMP	15	0	
CY8CTMA300EES	4016083	611028819	MB-PHIL	COMP	15	0	
CY8CTMA300EES	4021994	611028331	MB-PHIL	COMP	15	0	
<b>STRESS: DATA RETENTION, PLASTIC, 150C</b>							
CY8CTMA300EES	4016083	611021260	MB-PHIL	500	77	0	
CY8CTMA300EES	4016083	611021260	MB-PHIL	1000	77	0	
CY8CTMA300EES	4016083	611021260	MB-PHIL	1500	77	0	
<b>STRESS: HIGH TEMP DYNAMIC OPERATING LIFE-EARLY FAILURE RATE (150C, 2.07V, Vcc Max)</b>							
CY8CTMA300EES	4016083	611021260	MB-PHIL	48	500	0	
CY8CTMA300EES	4016083	611028818	MB-PHIL	48	1540	0	
CY8CTMA300EES	4021994	611028331	MB-PHIL	48	1528	0	
<b>STRESS: HIGH TEMP DYNAMIC OPERATING LIFE-EARLY FAILURE RATE REGULATOR ON (150C, 2.07V, Vcc Max)</b>							
CY8CTMA300EES	4021994	611028331	MB-PHIL	48	50	0	
<b>STRESS: HIGH TEMP DYNAMIC OPERATING LIFE-LATENT FAILURE RATE (150C, 2.07V, Vcc Max)</b>							
CY8CTMA300EES	4016083	611028818	MB-PHIL	80	118	0	
CY8CTMA300EES	4016083	611028818	MB-PHIL	500	116	0	
CY8CTMA300EES	4021994	611028331	MB-PHIL	80	116	0	
CY8CTMA300EES	4021994	611028331	MB-PHIL	500	115	0	
<b>STRESS: ENDURANCE</b>							
CY8CTMA300EES	4016083	611021260	MB-PHIL	168	80	0	
CY8CTMA300EES	4016083	611021260	MB-PHIL	500	80	0	
<b>STRESS: ESD-CHARGE DEVICE MODEL, (500V)</b>							
CY8CTMA300EES	4016083	611021260	MB-PHIL	COMP	9	0	
CY8CTMA300EES	4021994	611028331	MB-PHIL	COMP	9	0	
<b>STRESS: ESD-HUMAN BODY CIRCUIT PER JESD22, METHOD A114-B, (2,200V)</b>							
CY8CTMA300EES	4021994	611028331	MB-PHIL	COMP	8	0	



## Reliability Test Data

### QTP #:100101

<i>Device</i>	<i>Fab Lot #</i>	<i>Assy Lot #</i>	<i>Assy Lot</i>	<i>Duration</i>	<i>Samp</i>	<i>Rej</i>	<i>Failure Mechanism</i>
<b>STRESS: HI-ACCEL SATURATION TEST (130C, 85%RH, 5.5V), PRE COND 192 HR 30C/60%RH (MSL3)</b>							
CY8CTMA300EES	4021994	611028331	MB-PHIL	128	8	0	
<b>STRESS: PRESSURE COOKER TEST (121C, 100%RH), 15 Psig, PRE COND 192 HR 30C/60%RH (MSL3)</b>							
CY8CTMA300EES	4016083	611021260	MB-PHIL	168	80	0	
CY8CTMA300EES	4021994	611028331	MB-PHIL	168	80	0	
<b>STRESS: STATIC LATCH-UP (85C, 8.25V, 90mA)</b>							
CY8CTMA300EES	4021994	611028331	MB-PHIL	COMP	6	0	
<b>STRESS: TC COND. C -65C TO 150C, PRE COND 192 HRS 30C/60%RH (MSL3)</b>							
CY8CTMA300EES	4016083	611028818	MB-PHIL	500	80	0	
CY8CTMA300EES	4016083	611028819	MB-PHIL	500	80	0	
CY8CTMA300EES	4021994	611028331	MB-PHIL	500	80	0	



## Reliability Test Data

### QTP #:124505

<i>Device</i>	<i>Fab Lot #</i>	<i>Assy Lot #</i>	<i>Assy Lot</i>	<i>Duration</i>	<i>Samp</i>	<i>Rej</i>	<i>Failure Mechanism</i>
<b>STRESS: DATA RETENTION</b>							
CY8CTMA440 (8CC205001B)	4301809	611300880	CML-RA	500	80	0	
CY8CTMA440 (8CC205001B)	4301809	611300880	CML-RA	1000	79	0	
<b>STRESS: ENDURANCE</b>							
CY8CTMA440 (8CC205001B)	4301809	611300880	CML-RA	168	80	0	
CY8CTMA440 (8CC205001B)	4301809	611300880	CML-RA	500	80	0	
<b>STRESS: ESD-CHARGE DEVICE MODEL, (500V)</b>							
CY8CTMA440 (8CC205001B)	4301809	611300880	CML-RA	COMP	9	0	
<b>STRESS: ESD-CHARGE DEVICE MODEL, (750V)</b>							
CY8CTMA440 (8CC205002B)	4301809	6113011261	CML-RA	COMP	15	0	
<b>STRESS: ESD-HUMAN BODY CIRCUIT PER JESD22, METHOD A114, (2,200V)</b>							
CY8CTMA440 (8CC205001B)	4301809	611300880	CML-RA	COMP	8	0	
<b>STRESS: STATIC LATCH-UP (85C, 2.93V/8.25V, +/-140mA)</b>							
CY8CTMA440 (8CC205001B)	4301809	611300880	CML-RA	COMP	6	0	
<b>STRESS: HIGH TEMP DYNAMIC OPERATING LIFE-EARLY FAILURE RATE (150, 2.1V, Vcc Max)</b>							
CY8CTMA440 (8CC205001B)	4301809	611300880	CML-RA	48	498	0	
CY8CTMA440 (8CC205001B)	4301809	611300880	CML-RA	48	990	0	
CY8CTMA440 (8CC205001B)	4301809	611300880	CML-RA	48	827	0	
CY8CTMA440 (8CC205001B)	4301809	611300880	CML-RA	48	721	0	
CY8CTMA440 (8CC205001B)	4301809	611300880	CML-RA	48	594	0	
CY8CTMA445 (8CC205001B)	4301809	611304958	CML-RA	48	1205	1	Scan Failure
CY8CTMA445 (8CC205001B)	4301809	611304958	CML-RA	48	345	0	
CY8CTMA445 (8C205001B)	4301809	611306104	CML-RA	48	1382	0	
CY8CTMA445 (8C205001B)	4301809	611306104	CML-RA	48	168	0	
CY8CTMA445 (8C205001B)	4301809	611306104	CML-RA	48	756	0	



## Reliability Test Data

### QTP #:124505

<i>Device</i>	<i>Fab Lot #</i>	<i>Assy Lot #</i>	<i>Assy Lot</i>	<i>Duration</i>	<i>Samp</i>	<i>Rej</i>	<i>Failure Mechanism</i>
<b>STRESS: HIGH TEMP DYNAMIC OPERATING LIFE-LATENT FAILURE RATE (150C, 2.1V, Vcc Max)</b>							
CY8CTMA440 (8CC205001B)4301809	611300880	611300880	CML-RA	80	126	0	
CY8CTMA440 (8CC205001B)4301809	611300880	611300880	CML-RA	500	126	0	
<b>STRESS: TC COND. C -65C TO 150C, PRE COND 192 HRS 30C/60%RH (MSL3)</b>							
CY8CTMA440 (8CC205001B)4301809	611300880	611300880	CML-RA	500	80	0	
CY8CTMA440 (8CC205001B)4301809	611300880	611300880	CML-RA	1000	80	0	
<b>STRESS: PRESSURE COOKER TEST (121C, 100%RH), 15 Psig, PRE COND 192 HR 30C/60%RH (MSL3)</b>							
CY8CTMA440 (8CC205001B)4301809	611300880	611300880	CML-RA	168	80	0	



## Reliability Test Data

QTP #: 142304

Device	Fab Lot #	Assy Lot #	Assy Lot	Duration	Samp	Rej	Failure Mechanism
<b>STRESS: DATA RETENTION, 150C</b>							
CY8C4014 (8CP44304B)	5412006	611415880	CML-RA	500	80	0	
<b>STRESS: ENDURANCE, CYCLING + DATA BAKE (150C)</b>							
CY8C4014 (8CP44304B)	5412006	611415880	CML-RA	168	77	0	
<b>STRESS: ESD-CHARGE DEVICE MODEL (500V)</b>							
CY8C4014 (8CP44304B)	5412006	611415880	CML-RA	COMP	9	0	
<b>STRESS: ESD-CHARGE DEVICE MODEL (750V)</b>							
CY8C4014 (8CP44304B)	5412006	611415880	CML-RA	COMP	3	0	
<b>STRESS: ESD-CHARGE DEVICE MODEL (1000V)</b>							
CY8C4014 (8CP44304B)	5412006	611415880	CML-RA	COMP	3	0	
<b>STRESS: ESD-CHARGE DEVICE MODEL (1250V)</b>							
CY8C4014 (8CP44304B)	5412006	611415880	CML-RA	COMP	3	0	
<b>STRESS: ESD-CHARGE DEVICE MODEL (1500V)</b>							
CY8C4014 (8CP44304B)	5412006	611415880	CML-RA	COMP	3	0	
<b>STRESS: ESD-CHARGE DEVICE MODEL (1750V)</b>							
CY8C4014 (8CP44304B)	5412006	611415880	CML-RA	COMP	3	0	
<b>STRESS: ESD-HUMAN BODY CIRCUIT PER JESD22, METHOD A114-B (2,200V)</b>							
CY8C4014 (8CP44304B)	5412006	611415880	CML-RA	COMP	8	0	
<b>STRESS: ESD-HUMAN BODY CIRCUIT PER JESD22, METHOD A114-B (3,300V)</b>							
CY8C4014 (8CP44304B)	5412006	611415880	CML-RA	COMP	3	0	
<b>STRESS: ESD-HUMAN BODY CIRCUIT PER JESD22, METHOD A114-B (4,000V)</b>							
CY8C4014 (8CP44304B)	5412006	611415880	CML-RA	COMP	3	0	
<b>STRESS: ESD-HUMAN BODY CIRCUIT PER JESD22, METHOD A114-B (5,000V)</b>							
CY8C4014 (8CP44304B)	5412006	611415880	CML-RA	COMP	3	0	
<b>STRESS: ESD-HUMAN BODY CIRCUIT PER JESD22, METHOD A114-B (6,000V)</b>							
CY8C4014 (8CP44304B)	5412006	611415880	CML-RA	COMP	3	0	
<b>STRESS: ESD-MACHINE MODEL, (200V)</b>							
CY8C4014 (8CP44304B)	5412006	611415880	CML-RA	COMP	5	0	



## Reliability Test Data

QTP #: 142304

Device	Fab Lot #	Assy Lot #	Assy Lot	Duration	Samp	Rej	Failure Mechanism
<b>STRESS: STATIC LATCH-UP (85C, +/-140mA)</b>							
CY8C4014 (8CP44304B)	5412006	611415880	CML-RA	COMP	6	0	
<b>STRESS: STATIC LATCH-UP (85C, +/-200mA)</b>							
CY8C4014 (8CP44304B)	5412006	611415880	CML-RA	COMP	3	0	
<b>STRESS: STATIC LATCH-UP (125C, +/-140mA)</b>							
CY8C4014 (8CP44304B)	5412006	611415880	CML-RA	COMP	3	0	
<b>STRESS: STATIC LATCH-UP (85C, +/-300mA)</b>							
CY8C4014 (8CP44304B)	5412006	611415880	CML-RA	COMP	3	0	
<b>STRESS: HIGH TEMPERATURE DYNAMIC OPERATING LIFE-EARLY FAILURE RATE (150, 2.1V, Vcc Max)</b>							
CY8C4014 (8CP44304B)	5412006	611415880	CML-RA	48	1503	0	
<b>STRESS: HIGH TEMPERATURE DYNAMIC OPERATING LIFE-LATENT FAILURE RATE (150, 2.1V, Vcc Max)</b>							
CY8C4014 (8CP44304B)	5412006	611415880	CML-RA	80	118	0	
<b>STRESS: PRESSURE COOKER TEST</b>							
CY8C4014 (8CP44304B)	5412006	611415880	CML-RA	168	80	0	
<b>STRESS: TC COND. C -65 TO 150C, PRE COND 192 HRS 30C/60% RH (MSL3)</b>							
CY8C4014 (8CP44304B)	B5412006	611415880	CML-RA	500	80	0	



## Document History Page

Document Title: QTP#142304: QUALIFICATION OF CY8C4013 / CY8C4014 PSOC4 DEVICE FAMILY, S8PF-10R TECHNOLOGY, FAB3 HHGRACE  
Document Number: 001-92842

Rev.	ECN No.	Orig. of Change	Description of Change
**	4404221	HSTO	Initial Spec Release
*A	4411698	HSTO	Updated technology from S8P12-10R to S8PF-10R in title page and page 2. Updated Technology/Fab Process Description at page 3. Update Package Availability table at page 3. <ul style="list-style-type: none"><li>- Removed Au wire option</li><li>- Add 8L/16L SOIC package option</li><li>- Update assembly site name from ASE-G to ASE-K</li></ul>
*B	4624766	HSTO	Update Package Availability table <ul style="list-style-type: none"><li>- Add 28-Lead SSOP package</li></ul>

Distribution: WEB

Posting: None